

## Supporting Information

### Effects of Mg and Sn elements on the microstructure and properties of the Al-Zn-In-Ga sacrificial anode

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#### 1. Materials and methods

##### The polishing, cleaning, and sanitization processes in preparation of coupons

Before microstructural observation and electrochemical performance testing, the alloy samples were carefully prepared: first, they were wet-ground using 400#, 800#, 1000#, and 1500# sandpaper, followed by fine grinding with 800# and 1500# metallographic sandpaper, and finally polished with silicon carbide paste. Before the metallographic testing, the samples were etched using Keller's reagent for 15 seconds. Before the TEM test, the samples were mechanically ground to about 50  $\mu\text{m}$  and then cut into circular slices of 3 mm in diameter. The double-jet thinning voltage was set to 20 V, the temperature was -30  $^{\circ}\text{C}$  and the dual injection solution was 30%  $\text{HNO}_3$  and 70%  $\text{CH}_3\text{OH}$ .

##### 1.2. Sample pretreatment process for corrosion behaviour observation

After 7 days of corrosion, the samples were removed and immersed in a solution containing 68%  $\text{HNO}_3$ . They were then ultrasonically cleaned for 10 minutes to remove surface corrosion products. Subsequently, the samples were rinsed with distilled water and ultrasonically cleaned, then thoroughly rinsed with anhydrous ethanol solution. For samples used to calculate the self-corrosion rate, they were dried in a 50 $^{\circ}\text{C}$  oven for 1 hour before corrosion and after removing corrosion products, then weighed after moisture removal.

##### 1.3. The electrochemical measurements parameters

Open-circuit potential (OCP) was monitored for 300 seconds to ensure stability. Potential-driven polarization measurements were conducted within a voltage range of -1.6 to -0.5 V relative to the SCE, with a potential scan rate of 5 mV/s. Polarization curves were fitted using CView software. For EIS characterization, frequency scans covered a broad spectrum from  $10^5$  Hz to  $10^{-2}$  Hz, and the obtained spectra were subsequently modelled and interpreted using ZSimpWin analysis software.

##### 1.4. Anode current efficiency test setup

The current density settings for each experimental stage are detailed in Table .

**Table S1** Current density setting based on anode working area

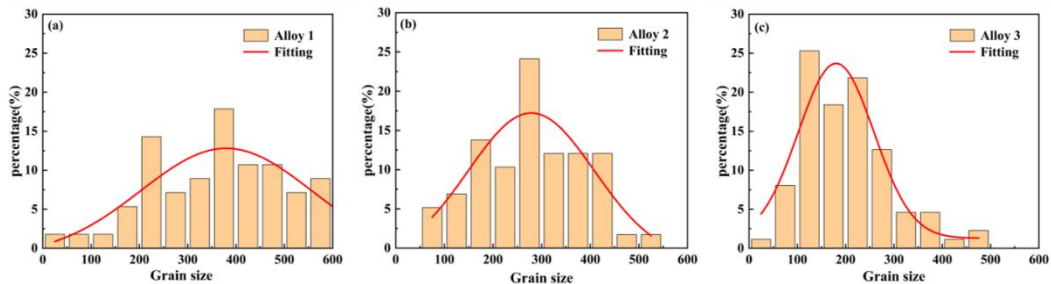
Time (h)	Current density ( $\text{mA cm}^{-2}$ )
0 ~ 24	1.5
> 24 ~ 48	0.4
> 48 ~ 72	4.0
> 72 ~ 96	1.5

## 2. Materials and methods Microstructure supplement experiment and analysis

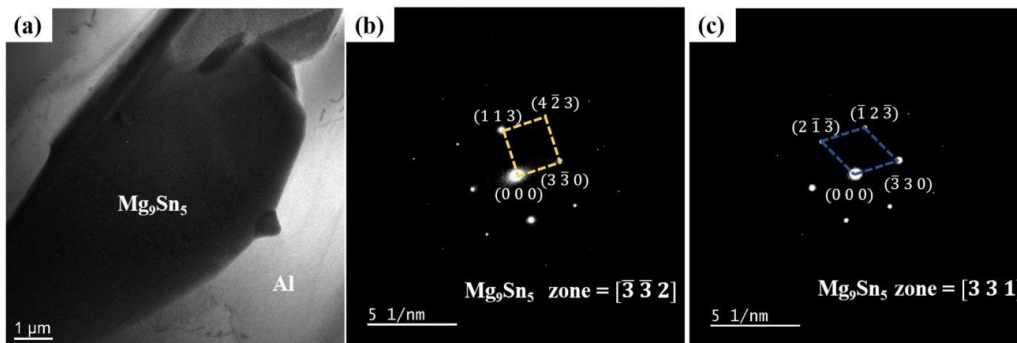
The grain sizes of the three alloys were quantitatively analyzed, and the resulting size distribution diagrams are presented in **Figure S1**. Adding Mg and Sn elements reduces the peak grain size from 375  $\mu\text{m}$  to 175  $\mu\text{m}$ . This result indicates that the Mg and Sn elements lead to grain size refinement in Al-Zn-In-Ga alloy.

To further determine the composition of the Mg-Sn-rich phases in Al-Zn-In-Ga-Mg-Sn alloy, the second phase was observed by TEM. **Figure S2** shows the TEM bright-field image and the corresponding selected area electron diffraction (SAED) pattern of the Al-Zn-In-Ga-Mg-Sn alloy, where Fig.5(a) shows the bright-field image and Fig.5(b, c) shows the diffraction patterns corresponding to the different crystallographic band axes of the phase. As shown in Fig.5(a), a larger Mg-Sn-rich phase can be observed. As shown in Fig.5(b), the crystal spacings of (113), ( $4\bar{2}3$ ) and ( $3\bar{3}0$ ) in the Mg-Sn-rich phase diffraction pattern along the  $[\bar{3}, \bar{3}, 2]$  band axis are 0.378, 0.271 and 0.387 nm, respectively. It is reported that the cellular parameters of  $\text{Mg}_9\text{Sn}_5$  are  $a=1.324$  nm,  $b=1.324$  nm,  $c=1.334$  nm,  $\alpha=\beta=90^\circ$ ,  $\gamma=120^\circ$ [1]. The corresponding crystallite spacings were calculated to be 0.3691 nm, 0.2655 nm, and 0.3822 nm, with an error of less than 5% between the measured and theoretical values. The measured angle between the (113) and ( $4\bar{2}3$ ) directions is  $44.41^\circ$ , and the measured angle between the (113) and ( $3\bar{3}0$ ) directions is  $90.16^\circ$ , which is consistent with the corresponding theoretical crystallographic interstitial angles of  $44.00^\circ$  and  $90^\circ$  in  $\text{Mg}_9\text{Sn}_5$ . Similarly, as shown in Fig.5(b), the crystal spacing of ( $2\bar{1}\bar{3}$ ), ( $\bar{3}30$ ), and ( $\bar{1}2\bar{3}$ ) in the Mg-Sn-rich phase pattern along the  $[3,3,1]$  band axis are 0.376, 0.387, and 0.376 nm, respectively. The corresponding crystallographic plane spacings are calculated from the cellular parameters of  $\text{Mg}_9\text{Sn}_5$  to 0.3691 nm, 0.3822 nm and 0.3691 nm, and the error between the measured and theoretical values is less than 5%. The measured angles between the ( $2\bar{1}\bar{3}$ ) and ( $\bar{1}2\bar{3}$ ) directions are  $58.03^\circ$  and between the ( $2\bar{1}\bar{3}$ ) and ( $\bar{3}30$ ) directions are  $119.01^\circ$ , which are in accordance with the corresponding theoretical crystallographic interfacial angles of  $57.75^\circ$  and  $118.87^\circ$ . In summary, the second phase in Al-Zn-In-Ga-Mg-Sn alloy is  $\text{Mg}_9\text{Sn}_5$ .

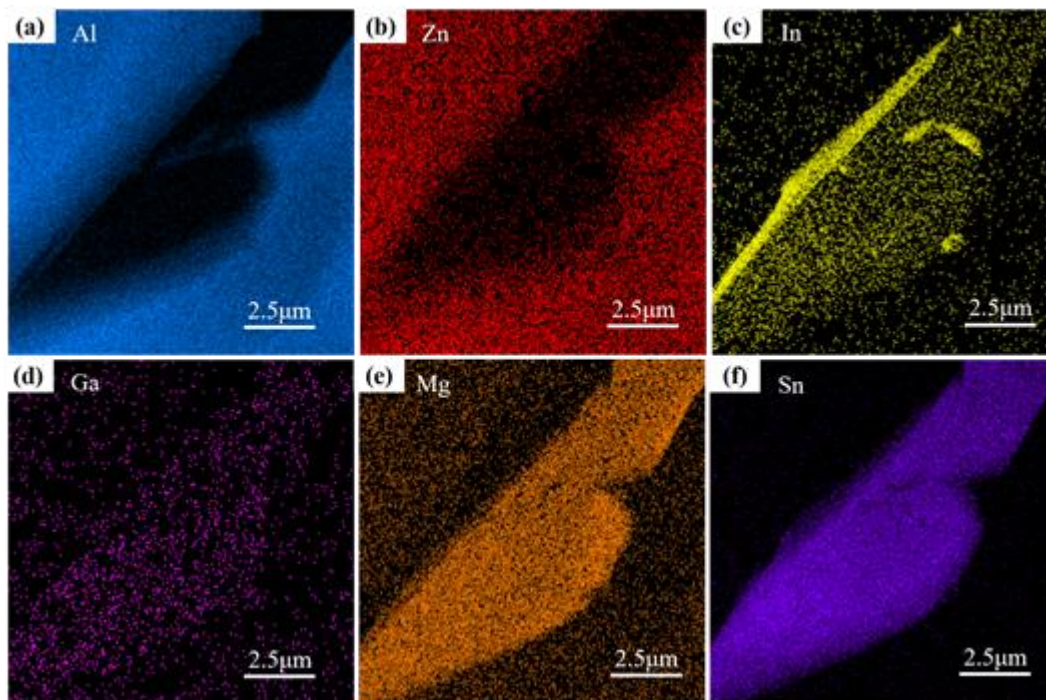
**Figure S3** shows the EDS results of the second phase transmission image. The second phase is mainly enriched with Mg and Sn elements, and there is a small amount of In element deposition.



**Figure S1** Grain size distribution of Al-Zn-In-Ga system sacrificial anodes (a)Al-5.5Zn-0.03In-0.03Ga, (b)Al-5.5Zn-0.03In-0.03Ga-1Mg, (c)Al-5.5Zn-0.03In-0.03Ga-1Mg-0.05Sn



**Figure S2** The TEM image of second phase in Al-Zn-In-Ga-Mg-Sn alloy (a)TEM bright field micrograph, (b, c)SAED patterns of precipitate along different directions electron beam incident directions



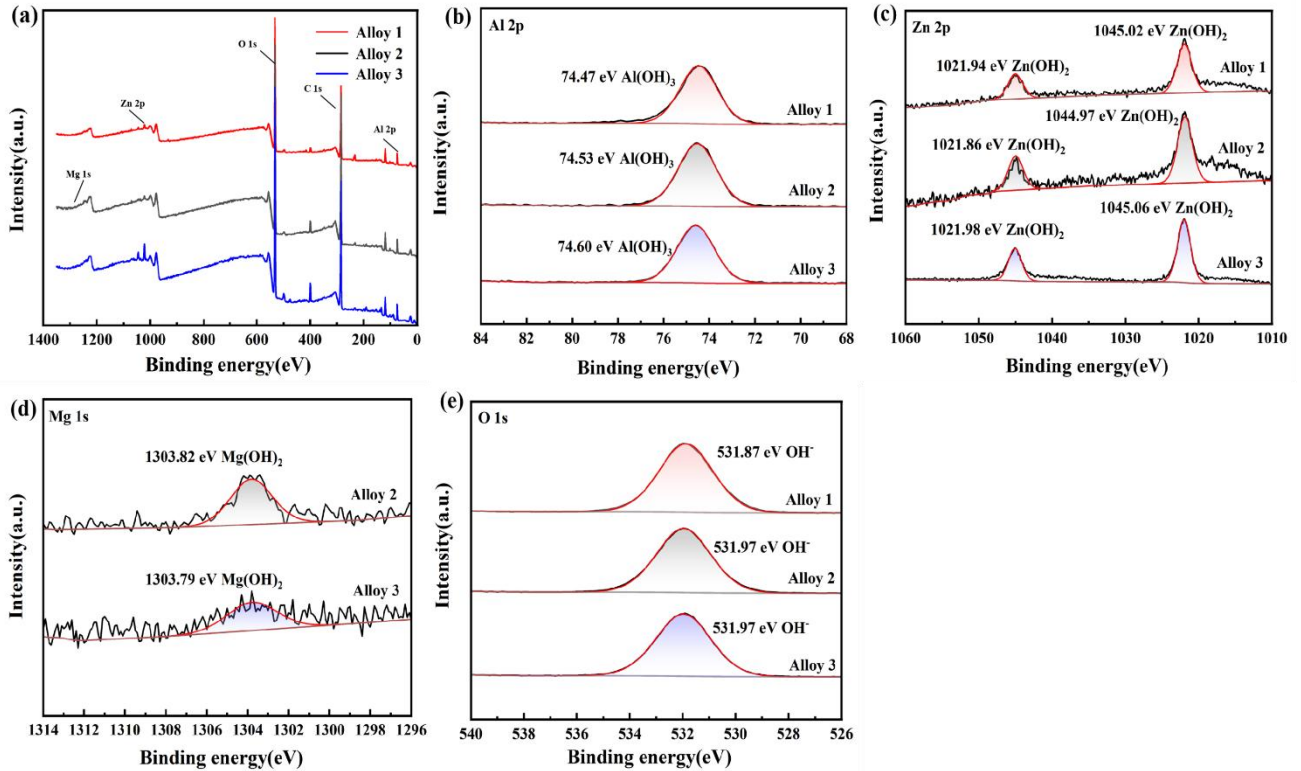
**Figure S3** EDS analysis results of the second-phase TEM image

## 2.2. Warburg impedance analysis

The Warburg impedance in this study can be attributed to the diffusion resistance of solution ions [2]. As the corrosion process progresses, corrosion products continuously accumulate on the electrode surface, forming a porous and uneven corrosion product film. This film allows solution ions to reach the substrate through defects or pores, thereby continuing the corrosion process. In this case, the film is unable to effectively block the current, so the resistance of the corrosion-resistant film is not significant. Therefore, the low-frequency electrochemical response of the system is primarily dominated by the diffusion of solution ions and corrosion products. Consequently, Warburg impedance is observed in the low-frequency region of the electrochemical impedance spectra of the three alloys.

## 2.3. XPS analysis of corrosion products

XPS spectra of the corrosion products are shown in **Figure S4**. The C peaks are from  $\text{CO}_2$  in solution and air, and the Al, O, Zn, and Mg peaks are from the alloys and the corrosion products. The binding energy was corrected for charge effects concerning the C 1s peak at 284.80 eV. **Figure S4** (a) shows the XPS total spectra of three Al-Zn-In-Ga alloys after corrosion 7d. **Figure S4** (b - e) shows the high-resolution spectra of Al 2p, Zn 2p, Mg 1s, and O 1s after 7 days of corrosion. The peaks of Al 2p are all located near the literature value (74.4 eV), which is derived from Al (III) [3]. The two spin-orbit split peaks of Zn 2p, 2p<sub>1</sub> (1044.8 eV) and 2p<sub>3</sub> (1021.8 eV), have a binding energy difference of 23 eV, corresponding to Zn(II) [4]. All peaks of Mg 1s are located near 1303.7 eV, corresponding to Mg(II) [5, 6]. The O 1s peaks of the three alloys are all located near the literature value (531.8 eV), which originates from  $\text{OH}^-$  [5]. These results indicate that the primary corrosion products of the three alloys are  $\text{Al}(\text{OH})_3$  and  $\text{Zn}(\text{OH})_2$ . Additionally, the corrosion products of the Al-Zn-In-Ga-Mg and Al-Zn-In-Ga-Mg-Sn alloys contain trace amounts of  $\text{Mg}(\text{OH})_2$ .



**Figure S4** XPS spectra of three Al-Zn-In-Ga alloys after corrosion in 3.5% NaCl solution for 7 d (a)survey spectra, (b)Al 2p spectrum, (c)Zn 2p spectrum, (d)Mg 1s spectrum, (e)O 1s spectrum.

## References

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